

**TRANSMITTAL OF FORMAL DRAWINGS**Docket No.
YOR920030323US1 (16890)Invention Application Of: **Diane C. Boyd, et al.**

Serial No.	Filing Date	Confirmation No.	Examiner	Art Unit
10/725,849	December 2, 2003	Unassigned	Unassigned	Unassigned

Invention: **ULTRA-THIN Si CHANNEL MOSFET USING A SELF-ALIGNED OXYGEN IMPLANT AND DAMASCENE TECHNIQUE**Address to:
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Transmitted herewith are:

6 sheets of formal drawing(s) for this application.

☒ Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

Signature

Steven Fischman
Registration No. 34,594
SCULLY, SCOTT, MURPHY & PRESSER
400 Garden City Plaza
Garden City, New York 11530
(516) 742-4343
LSS:HAH:kcDated: **February 24, 2004**I certify that this document and attached formal drawings are being deposited on **February 24, 2004** with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Signature

Steven Fischman

Typed or Printed Name